TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSIII)

2SK2605

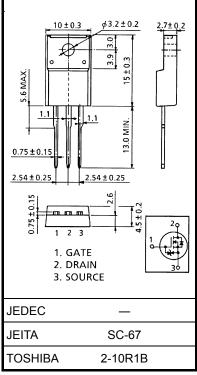
Switching Regulator Applications

Unit: mm

• Low drain–source ON resistance : $R_{DS\ (ON)} = 1.9\ \Omega\ (typ.)$ • High forward transfer admittance : $|Y_{fs}| = 3.8\ S\ (typ.)$ • Low leakage current : $I_{DSS} = 100\ \mu A\ (max)\ (V_{DS} = 640\ V)$ • Enhancement mode : $V_{th} = 2.0\ to\ 4.0\ V\ (V_{DS} = 10\ V,\ I_D = 1\ mA)$

Absolute Maximum Ratings (Ta = 25°C)

| Characteris | stics | Symbol | Rating | Unit |
|-------------------------|------------------------|------------------|------------|------|
| Drain-source voltage | | V_{DSS} | 800 | V |
| Drain-gate voltage (Ro | _{SS} = 20k Ω) | V_{DGR} | 800 | V |
| Gate-source voltage | | V _{GSS} | ±30 | V |
| Drain current | DC (Note 1) | ΙD | 5 | Α |
| | Pulse (Note 1) | I _{DP} | 15 | Α |
| Drain power dissipation | n (Tc = 25°C) | P_{D} | 45 | W |
| Single pulse avalanche | e energy (Note 2) | E _{AS} | 370 | mJ |
| Avalanche current | | I _{AR} | 5 | Α |
| Repetitive avalanche e | nergy (Note 3) | E _{AR} | 4.5 | mJ |
| Channel temperature | | T _{ch} | 150 | °C |
| Storage temperature ra | ange | T _{stg} | -55 to 150 | °C |



Weight: 1.9 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 2.78 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 62.5 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 27 mH, R_G = 25 Ω , I_{AR} = 5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

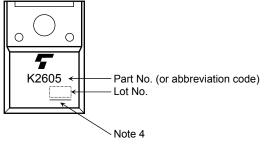
Electrical Characteristics (Ta = 25°C)

| Charac | cteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-----------------|----------------------|--|-----|------|-----|------|
| Gate leakage cu | ırrent | I _{GSS} | V _{GS} = ±30 V, V _{DS} = 0 V | | _ | ±10 | μΑ |
| Gate-source bre | eakdown voltage | V (BR) GSS | I _G = ±10 μA, V _{DS} = 0 V | ±30 | _ | _ | V |
| Drain cut-off cu | rrent | I _{DSS} | V _{DS} = 640 V, V _{GS} = 0 V | _ | _ | 100 | μΑ |
| Drain-source br | eakdown voltage | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 800 | _ | _ | V |
| Gate threshold v | oltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | _ | 4.0 | V |
| Drain-source O | N resistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 3 A, | _ | 1.9 | 2.2 | Ω |
| Forward transfer | r admittance | Y _{fs} | V _{DS} = 15 V, I _D = 3 A | 1.0 | 3.8 | _ | S |
| Input capacitano | e | C _{iss} | | _ | 1080 | _ | |
| Reverse transfer capacitance | | C _{rss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | _ | 16 | _ | pF |
| Output capacitance | | Coss | 1 | | 105 | _ | |
| Switching time | Rise time | t _r | $V_{GS} = \frac{10V}{0V}$ V_{Out} $R_{L} = 66.7\Omega$ $V_{DD} = 200V$ | _ | 40 | _ | - ns |
| | Turn-on time | t _{on} | | _ | 80 | _ | |
| | Fall time | t _f | | _ | 40 | _ | |
| | Turn-off time | t _{off} | $Duty \le 1\%, t_{\mathbf{W}} = 10 \mu s$ | _ | 140 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | | | 34 | _ | |
| Gate-source charge | | Q _{gs} | $V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}$ | | 16 | | nC |
| Gate-drain ("miller") Charge | | Q _{gd} | | | 18 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 5 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 15 | Α |
| Forward voltage (diode) | V_{DSF} | I _{DR} = 5 A, V _{GS} = 0 V | _ | _ | -1.9 | V |
| Reverse recovery time | t _{rr} | I _{DR} = 5 A, V _{GS} = 0 V, dI _{DR} / dt = 100 A / μs | 1 | 1000 | - | ns |
| Reverse recovery charge | Q _{rr} | TDR = 3 A, VGS = 0 V, αιDR / αι = 100 A / μs | | 7.5 | | μC |

Marking

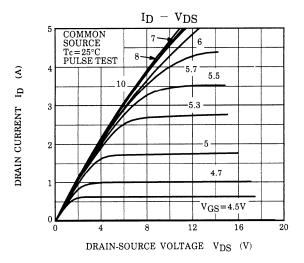


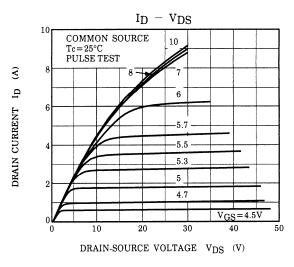
Note 4: A line under a Lot No. identifies the indication of product Labels.

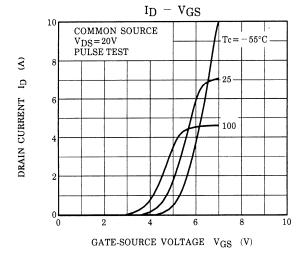
Not underlined: [[Pb]]/INCLUDES > MCV

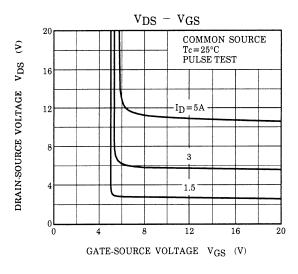
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

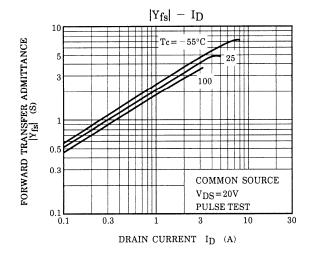
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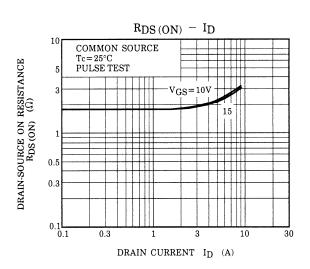




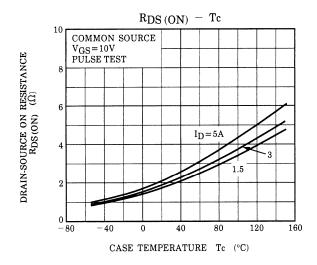


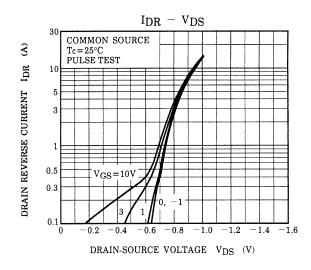


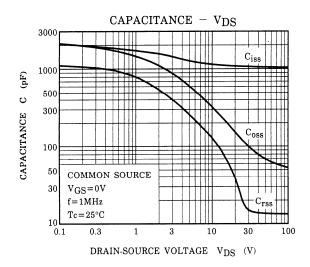


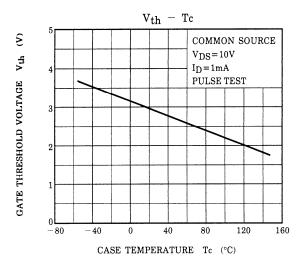


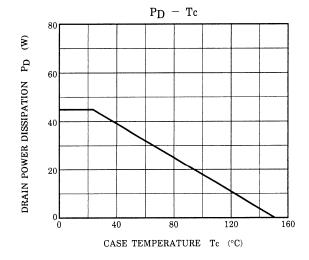
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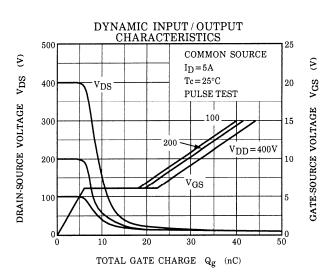




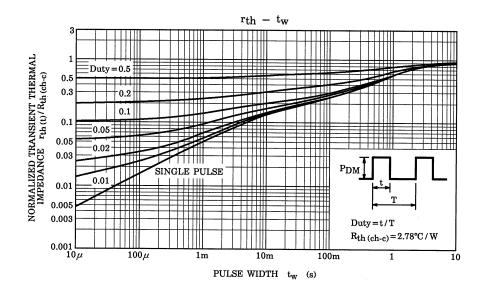


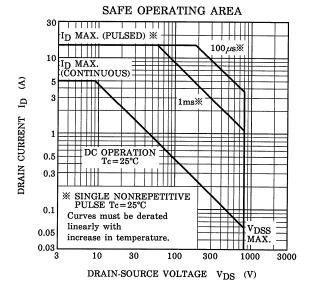


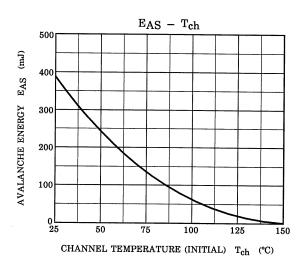


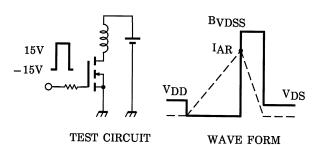


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$$\begin{aligned} &RG = 25 \ \Omega \\ &V_{DD} = 90 \ V, \ L = 27 \ mH \end{aligned} \qquad E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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